General Description
The AAT2113B SwitchReg™ is a 1.5A step-down converter with a typical input voltage of 3.3V and a fixed output voltage of 1.2V or an adjustable output. The 3.3MHz switching frequency enables the use of small external components. The ultra-small 2mm x 2mm footprint and high efficiency make the AAT2113B an ideal choice for portable applications.

The AAT2113B delivers 1.5A maximum output current while consuming only 55μA no-load quiescent current. Low R_DSON integrated MOSFETs and 100% duty cycle operation make the AAT2113B the ideal choice for high output voltage, high current applications which require a low dropout threshold.

The AAT2113B provides excellent transient response and output accuracy across the operating range. No external compensation is required.

The AAT2113B maintains high efficiency throughout the load range. The unique low-noise architecture reduces ripple and spectral noise. The AAT2113B automatically optimizes efficiency during Light Load mode (LL) and maintains constant frequency and low output ripple during PWM mode.

Over-temperature and short circuit protection safeguard the AAT2113B and system components from damage.

The AAT2113B is available in a Pb-free, ultra-small, low profile, 8-pin 2mm x 2mm FTDFN package. The product is rated over a temperature range of -40°C to 85°C.

Features
- 5mm x 5mm Total Solution Size
- 1.5A Maximum Output Current
- Tiny 0.47μH Chip Inductor
- Excellent Transient Response
- Input Voltage: 2.7V to 5.5V
- Ultra-small, Low Profile 8-pin 2mm x 2mm FTDFN Package
- Fixed or Adjustable Output Voltage Options:
  - Fixed Output Voltage: 1.2V
  - Adjustable Output Voltage: 1.0V to 2.5V
- High Efficiency, Low Noise Architecture
- 3.3MHz Switching Frequency
- No External Compensation Required
- 55μA No Load Quiescent Current
- 100% Duty Cycle Low-Dropout Operation
- Internal Soft Start
- Over-Temperature and Current Limit Protection
- <1μA Shutdown Current
- -40°C to 85°C Temperature Range

Applications
- Cellular Phones
- Digital Cameras
- Hard Disk Drives
- MP3 Players
- PDAs and Handheld Computers
- Portable Media Players
- USB Devices
- Wireless Network Cards

Typical Application

![Typical Application Diagram](https://www.skyworksinc.com/data/skyworks/2113b.jpg)

Load Transient Response
(VIN = 5V; VOUT = 1.2V; IOUT = 10% to 100%; COUT = 10μF, 6.3V, 0603)

- VIN: 2.7V to 5.5V
- VOUT: 1.2V/1.5A
- L1: 0.47μH
- C1: 4.7μF
- C3: 10µF
- 1.0µF
- 6.3V
- 0603
- 0402
- 0603

Skyworks Solutions, Inc. • Phone [781] 376-3000 • Fax [781] 376-3100 • sales@skyworksinc.com • www.skyworksinc.com
Pin Descriptions

<table>
<thead>
<tr>
<th>Pin #</th>
<th>Symbol</th>
<th>Function</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>PGND</td>
<td>Main power ground return pin. Connect to the output and input capacitor return.</td>
</tr>
<tr>
<td>2</td>
<td>VP</td>
<td>Input power supply tied to the source of the high side P-channel MOSFET.</td>
</tr>
<tr>
<td>3</td>
<td>VCC</td>
<td>Power supply; supplies power for the internal circuitry.</td>
</tr>
<tr>
<td>4</td>
<td>FB</td>
<td>Feedback input pin. This pin is connected directly to the converter output for the 1.2V fixed output version, or connected to an external resistor divider for the adjustable output version.</td>
</tr>
<tr>
<td>5</td>
<td>AGND</td>
<td>Analog ground. This pin is internally connected to the analog ground of the control circuitry.</td>
</tr>
<tr>
<td>6</td>
<td>EN</td>
<td>Enable pin. A logic low disables the converter and it consumes less than 1μA of current. When connected high, it resumes normal operation.</td>
</tr>
<tr>
<td>7, 8</td>
<td>LX</td>
<td>Switching node. Connect the inductor to this pin. It is internally connected to the drain of both high and low side MOSFETs.</td>
</tr>
</tbody>
</table>

Pin Configuration

FTDFN22-8
(Top View)

```
PGND   LX
VP     LX
VCC    EN
FB     AGND
```
### Absolute Maximum Ratings

$T_A = 25^\circ C$ unless otherwise noted.

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
<th>Value</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CC}$, $V_P$</td>
<td>$V_P$, $V_{CC}$ to GND</td>
<td>6.0</td>
<td>V</td>
</tr>
<tr>
<td>$V_LX$</td>
<td>$LX$ to GND</td>
<td>-0.3 to $V_P + 0.3$</td>
<td>V</td>
</tr>
<tr>
<td>$V_FB$</td>
<td>$FB$ to GND</td>
<td>-0.3 to $V_P + 0.3$</td>
<td>V</td>
</tr>
<tr>
<td>EN</td>
<td>EN to GND</td>
<td>-0.3 to $V_{CC} + 0.3$</td>
<td>V</td>
</tr>
<tr>
<td>$T_J$</td>
<td>Operating Junction Temperature Range</td>
<td>-40 to 150</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{LEAD}$</td>
<td>Maximum Soldering Temperature (at leads, 10 sec.)</td>
<td>300</td>
<td>°C</td>
</tr>
</tbody>
</table>

### Thermal Characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
<th>Value</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Theta_{JA}$</td>
<td>Maximum Thermal Resistance</td>
<td>70</td>
<td>°C/W</td>
</tr>
<tr>
<td>$P_D$</td>
<td>Maximum Power Dissipation$^{1, 2, 3}$</td>
<td>1.4</td>
<td>W</td>
</tr>
</tbody>
</table>

1. Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum Rating should be applied at any one time.
2. Mounted on an FR4 board.
3. Derate 14$mW/°C$ above 25°C.
## Electrical Characteristics

\( V_{IN} = 3.3 \text{V}, T_A = -40^\circ \text{C} \) to 85°C unless otherwise noted. Typical values are at \( T_A = 25^\circ \text{C} \).

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{IN} )</td>
<td>Input Voltage</td>
<td></td>
<td>2.7</td>
<td>3.3</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>( V_{OUT} )</td>
<td>Output Voltage Range</td>
<td></td>
<td>1</td>
<td>1.2</td>
<td>2.5</td>
<td>V</td>
</tr>
<tr>
<td>( V_{UVLO} )</td>
<td>UVLO Threshold</td>
<td>( V_{IN} ) rising</td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Hysteresis</td>
<td>2.4</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{IN} ) falling</td>
<td>1.6</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>( V_{OUT} )</td>
<td>Output Voltage Tolerance</td>
<td>( I_{OUT} = 0 ) A to 1.5A, ( V_{IN} = 3.3 \text{V}, V_{OUT} = 1.2 \text{V} ) fixed</td>
<td>-3.0</td>
<td></td>
<td>+3.0</td>
<td>%</td>
</tr>
<tr>
<td>( I_Q )</td>
<td>Quiescent Current</td>
<td>No Load</td>
<td>55</td>
<td>90</td>
<td></td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>( I_{SHDN} )</td>
<td>Shutdown Current</td>
<td>( EN = \text{GND} )</td>
<td>1.0</td>
<td></td>
<td></td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>( I_{IH} )</td>
<td>Current Limit</td>
<td></td>
<td>2</td>
<td>3</td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>( R_{DS(on)H} )</td>
<td>High Side Switch On-Resistance</td>
<td></td>
<td>140</td>
<td></td>
<td></td>
<td>m( \Omega )</td>
</tr>
<tr>
<td>( R_{DS(on)L} )</td>
<td>Low Side Switch On-Resistance</td>
<td></td>
<td>100</td>
<td></td>
<td></td>
<td>m( \Omega )</td>
</tr>
<tr>
<td>( \Delta V_{LOADREG} )</td>
<td>Load Regulation</td>
<td>( I_{LOAD} = 0 ) A to 1.5A</td>
<td>0.5</td>
<td></td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>( \Delta V_{LINEDER}/\Delta V_{IN} )</td>
<td>Line Regulation</td>
<td>( V_{IN} = 3.3 \text{V} ) to 4.0V</td>
<td>0.3</td>
<td></td>
<td></td>
<td>%/V</td>
</tr>
<tr>
<td>( V_{FB} )</td>
<td>Feedback Threshold Voltage Accuracy (Adjustable Version)</td>
<td>No load, ( T_A = 25^\circ \text{C} )</td>
<td>0.591</td>
<td>0.60</td>
<td>0.609</td>
<td>V</td>
</tr>
<tr>
<td>( I_{LX,LEAK,R} )</td>
<td>LX Reverse Leakage Current</td>
<td>( V_{IN} ) unconnected, ( V_{LX} = 5.5 \text{V}, EN = \text{GND} )</td>
<td>1.0</td>
<td></td>
<td></td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>( I_{FBLEAK} )</td>
<td>FB Leakage Current</td>
<td>( V_{OUT} = 1.2 \text{V} )</td>
<td>0.2</td>
<td></td>
<td></td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>( F_{OSC} )</td>
<td>Internal Oscillator Frequency</td>
<td></td>
<td>2.6</td>
<td>3.3</td>
<td>3.8</td>
<td>MHz</td>
</tr>
<tr>
<td>( T_s )</td>
<td>Start-up Time</td>
<td>Enable to Output Regulation</td>
<td>60</td>
<td></td>
<td></td>
<td>( \mu \text{s} )</td>
</tr>
<tr>
<td>( T_{SO} )</td>
<td>Over-Temperature Shutdown Threshold</td>
<td></td>
<td>140</td>
<td></td>
<td></td>
<td>( ^\circ \text{C} )</td>
</tr>
<tr>
<td>( T_{HYS} )</td>
<td>Over-Temperature Shutdown Hysteresis</td>
<td></td>
<td>25</td>
<td></td>
<td></td>
<td>( ^\circ \text{C} )</td>
</tr>
</tbody>
</table>

### EN Logic

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{IL} )</td>
<td>EN Threshold Low</td>
<td></td>
<td></td>
<td>0.4</td>
<td>V</td>
</tr>
<tr>
<td>( V_{IH} )</td>
<td>EN Threshold High</td>
<td></td>
<td></td>
<td>1.4</td>
<td>V</td>
</tr>
<tr>
<td>( I_{LEAK} )</td>
<td>EN Leakage Current</td>
<td>( V_{EN} = 5.5 \text{V} )</td>
<td>-1.0</td>
<td></td>
<td>1.0</td>
</tr>
</tbody>
</table>

1. The AAT2113B is guaranteed to meet performance specifications over the -40°C to +85°C operating temperature range and is assured by design, characterization, and correlation with statistical process controls.
Typical Characteristics

**Efficiency vs. Output Current**  
\(V_{\text{OUT}} = 1.2\text{V}; L = 0.47\mu\text{H}\)

<table>
<thead>
<tr>
<th>Output Current (mA)</th>
<th>Efficiency (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td></td>
</tr>
<tr>
<td>10</td>
<td></td>
</tr>
<tr>
<td>100</td>
<td></td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)
- \(V_{\text{IN}} = 2.7\text{V}\)

**Load Regulation**  
\(V_{\text{OUT}} = 1.2\text{V}; L = 0.47\mu\text{H}\)

<table>
<thead>
<tr>
<th>Output Current (mA)</th>
<th>Load Regulation (%)</th>
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</thead>
<tbody>
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<td></td>
</tr>
<tr>
<td>100</td>
<td></td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)
- \(V_{\text{IN}} = 2.7\text{V}\)

**Efficiency vs. Output Current**  
\(V_{\text{OUT}} = 1.8\text{V}; L = 0.82\mu\text{H}\)

<table>
<thead>
<tr>
<th>Output Current (mA)</th>
<th>Efficiency (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td></td>
</tr>
<tr>
<td>10</td>
<td></td>
</tr>
<tr>
<td>100</td>
<td></td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)
- \(V_{\text{IN}} = 2.7\text{V}\)

**Load Regulation**  
\(V_{\text{OUT}} = 1.8\text{V}; L = 0.82\mu\text{H}\)

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<thead>
<tr>
<th>Output Current (mA)</th>
<th>Load Regulation (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td></td>
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<td></td>
</tr>
<tr>
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</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)

**Efficiency vs. Output Current**  
\(V_{\text{OUT}} = 2.5\text{V}; L = 1\mu\text{H}\)

<table>
<thead>
<tr>
<th>Output Current (mA)</th>
<th>Efficiency (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td></td>
</tr>
<tr>
<td>10</td>
<td></td>
</tr>
<tr>
<td>100</td>
<td></td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)

**Load Regulation**  
\(V_{\text{OUT}} = 2.5\text{V}; L = 1\mu\text{H}\)

<table>
<thead>
<tr>
<th>Output Current (mA)</th>
<th>Load Regulation (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td></td>
</tr>
<tr>
<td>10</td>
<td></td>
</tr>
<tr>
<td>100</td>
<td></td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>10000</td>
<td></td>
</tr>
</tbody>
</table>

- \(V_{\text{IN}} = 5.5\text{V}\)
- \(V_{\text{IN}} = 5.0\text{V}\)
- \(V_{\text{IN}} = 4.2\text{V}\)
- \(V_{\text{IN}} = 3.6\text{V}\)
- \(V_{\text{IN}} = 3.0\text{V}\)
Typical Characteristics

Output Voltage Error vs. Temperature
\( V_{\text{OUT}} = 1.2V; V_{\text{IN}} = 3.3V; I_{\text{OUT}} = 1A \)

Output Voltage Error vs. Temperature
\( V_{\text{OUT}} = 1.8V; I_{\text{OUT}} = 1A \)

Output Voltage Error vs. Temperature
\( V_{\text{OUT}} = 2.5V; I_{\text{OUT}} = 1A \)
Typical Characteristics

Switching Frequency vs. Temperature
(I\textsubscript{OUT} = 1A)

Quiescent Current vs. Input Voltage
(No Load)

Load Transient
(V\textsubscript{OUT} = 1.2V; V\textsubscript{IN} = 3.3V; I\textsubscript{OUT} = 0 to 1.5A; C\textsubscript{OUT} = 10\mu F)

Load Transient
(V\textsubscript{OUT} = 1.8V; V\textsubscript{IN} = 3.3V; I\textsubscript{OUT} = 0 to 1.5A; C\textsubscript{OUT} = 10\mu F)

Load Transient
(V\textsubscript{OUT} = 1.2V; V\textsubscript{IN} = 3.3V; I\textsubscript{OUT} = 75mA to 1350mA; C\textsubscript{OUT} = 10\mu F)

Load Transient
(V\textsubscript{OUT} = 1.8V; V\textsubscript{IN} = 3.3V; I\textsubscript{OUT} = 75mA to 1350mA; C\textsubscript{OUT} = 10\mu F)
Typical Characteristics

**Load Transient**
(V_{OUT} = 2.5V; V_{IN} = 3.6V; I_{OUT} = 0 to 1.5A; C_{OUT} = 10µF)

**Load Transient**
(V_{OUT} = 2.5V; V_{IN} = 3.6V; I_{OUT} = 75mA to 1350mA; C_{OUT} = 10µF)

**Line Transient**
(V_{OUT} = 1.2V; V_{IN} = 3.3V to 3.6V; I_{OUT} = 1A)

**Line Transient**
(V_{OUT} = 1.8V; V_{IN} = 3.3V to 3.6V; I_{OUT} = 1A)

**Line Regulation**
(V_{OUT} = 1.2V; L = 0.47µH)

**Line Regulation**
(V_{OUT} = 1.8V; L = 0.47µH)
Typical Characteristics

Line Regulation
\( (V_{\text{OUT}} = 2.5V; L = 1\mu H) \)

[Graph showing line regulation with input voltage (V) and line regulation (%) for different current levels: I_{\text{OUT}} = 1500mA, 1000mA, 500mA, 1mA.]

Soft Start
\( (V_{\text{OUT}} = 1.2V; V_{\text{IN}} = 3.3V; I_{\text{OUT}} = 1A) \)

[Graph showing soft start with time (100µs/div), enable voltage (top), output voltage (middle), and inductor current (bottom).]

Output Voltage Ripple
\( (V_{\text{OUT}} = 1.2V; V_{\text{IN}} = 3.3V; I_{\text{OUT}} = 1.5A) \)

[Graph showing output voltage ripple with time (200ns/div), output voltage (top), and inductor current (bottom).]

Output Voltage Ripple
\( (V_{\text{OUT}} = 1.2V; V_{\text{IN}} = 3.3V; I_{\text{OUT}} = 1mA) \)

[Graph showing output voltage ripple with time (10µs/div), output voltage (top), and inductor current (bottom).]
## Typical Characteristics

**Output Voltage Ripple**  
\( V_{\text{OUT}} = 1.8\,\text{V}; \quad V_{\text{IN}} = 3.3\,\text{V}; \quad I_{\text{OUT}} = 1.5\,\text{A} \)

![Graph showing output voltage ripple with time (200ns/div) and inductor current (500mA/div).](image)

**Output Voltage Ripple**  
\( V_{\text{OUT}} = 2.5\,\text{V}; \quad V_{\text{IN}} = 3.3\,\text{V}; \quad I_{\text{OUT}} = 1\,\text{mA} \)

![Graph showing output voltage ripple with time (50µs/div) and inductor current (100mA/div).](image)
### Functional Description

The AAT2113B SwitchReg is a 1.5A step-down converter with a typical input voltage of 3.3V and a fixed output voltage of 1.2V. The 3.3MHz switching frequency enables the use of small external components. The ultra-small, 2mm x 2mm footprint and high efficiency make the AAT2113B an ideal choice for portable applications. Typically, a 0.47μH inductor and a 10μF ceramic capacitor are recommended for a 1.2V output (see Figure 2 for recommended values).

At dropout, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the $R_{DS(on)}$ drop of the P-channel high-side MOSFET (plus the DC drop of the external inductor). The device integrates extremely low $R_{DS(on)}$ MOSFETs to achieve low dropout voltage during 100% duty cycle operation.

The integrated low-loss MOSFET switches can provide excellent efficiency at heavy loads. Light load operation maintains high efficiency, low ripple and low spectral noise even at lower currents (typically <150mA). PWM mode operation maintains constant frequency and low output ripple at output loads greater than 200mA.

In battery-powered applications, as $V_{IN}$ decreases, the converter dynamically adjusts the operating frequency prior to dropout to maintain the required duty cycle and provide accurate output regulation. Output regulation is maintained until the dropout voltage, or minimum input voltage, is reached. At 1.5A output load, dropout voltage headroom is approximately 200mV.

The AAT2113B typically achieves better than ±0.5% output regulation across the input voltage and output load range. A current limit of 3.0A (typical) protects the IC and system components from short-circuit damage. Typical no load quiescent current is 55μA.

Thermal protection completely disables switching when the maximum junction temperature is detected. The junction over-temperature threshold is 140°C with 25°C of hysteresis. Once an over-temperature or over-current fault condition is removed, the output voltage automatically recovers.

Peak current mode control and optimized internal compensation provide high loop bandwidth and excellent response to input voltage and fast load transient events. Soft start eliminates output voltage overshoot when the enable or the input voltage is applied. Under-voltage lockout prevents spurious start-up events.
Control Loop

The AAT2113B is a peak current mode step-down converter. The current through the P-channel MOSFET (high side) is sensed for current loop control, as well as short-circuit and overload protection. A fixed slope compensation signal is added to the sensed current to maintain stability for duty cycles greater than 50%. The peak current mode loop appears as a voltage-programmed current source in parallel with the output capacitor.

The output of the voltage error amplifier programs the current mode loop for the necessary peak switch current to force a constant output voltage for all load and line conditions. Internal loop compensation terminates the transconductance voltage error amplifier output. The reference voltage is internally set to program the converter output voltage greater than or equal to 0.6V.

Soft Start/Enable

Soft start limits the current surge seen at the input and eliminates output voltage overshoot. The enable input, when pulled low, forces the AAT2113B into a low-power, non-switching state. The total input current during shutdown is less than 1μA.

Current Limit and Over-Temperature Protection

For overload conditions, the peak input current is limited. To minimize power dissipation and stresses under current limit and short-circuit conditions, switching is terminated after entering current limit for a series of pulses. Switching is terminated for seven consecutive clock cycles after a current limit has been sensed for a series of four consecutive clock cycles.

Thermal protection completely disables switching when internal dissipation becomes excessive. The junction over-temperature threshold is 140°C with 25°C of hysteresis. Once an over-temperature or over-current fault condition is removed, the output voltage automatically recovers.

Under-Voltage Lockout

Internal bias of all circuits is controlled via the VCC input. Under-voltage lockout (UVLO) guarantees sufficient V_{IN} bias and proper operation of all internal circuitry prior to activation.

Component Selection

Inductor Selection

The step-down converter uses peak current mode control with slope compensation to maintain stability for duty cycles greater than 50%. The output inductor value must be selected so the inductor current down slope meets the internal slope compensation requirements.

For applications where the duty cycle is less than 50%, the inductor values can be chosen freely.

Manufacturer’s specifications list both the inductor DC current rating, which is a thermal limitation, and the peak current rating, which is determined by the saturation characteristics. The inductor should not show any appreciable saturation under normal load conditions.

Some inductors may meet the peak and average current ratings yet result in excessive losses due to a high DCR. Always consider the losses associated with the DCR and its effect on the total converter efficiency when selecting an inductor.

For low cost application and a sufficiently small footprint in a 5x5mm area, the LQM2HPNR47MG0 shielded chip inductor, which has 40mΩ DCR and 1.8A DC current rating, is selected for 1.2V output.

The inductors listed in Table 1 have been used with the AAT2113B.

<table>
<thead>
<tr>
<th>Manufacturer</th>
<th>Part Number</th>
<th>Value (μH) ±20%</th>
<th>DC Resistance (Ω) ±25%</th>
<th>Size (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Murata</td>
<td>LQM2HPNR47MG0</td>
<td>0.47 ±20%</td>
<td>0.04 ±25%</td>
<td>2.5x2.0x1.0</td>
</tr>
<tr>
<td>Coilcraft</td>
<td>EPL2010-421ML</td>
<td>0.42 ±20%</td>
<td>0.04 ±25%</td>
<td>2.0x2.0x1.0</td>
</tr>
<tr>
<td></td>
<td>EPL2010-681ML</td>
<td>0.68 ±20%</td>
<td>0.058 ±25%</td>
<td>2.0x2.0x1.0</td>
</tr>
</tbody>
</table>

Table 1: AAT2113B List of Inductors.
Input Capacitor

Select a 4.7\( \mu \)F to 10\( \mu \)F X7R or X5R ceramic capacitor for the input. To estimate the required input capacitor size, determine the acceptable input ripple level (\( \frac{V_{PP}}{V_{DD}} \)) and solve for \( C \). The calculated value varies with input voltage and is a maximum when \( V_{IN} \) is double the output voltage.

\[
C_{IN} = \frac{V_{O} \cdot (1 - \frac{V_{O}}{V_{IN}})}{\left( \frac{V_{PP}}{I_{O}} - \text{ESR} \right) \cdot F_{S}}
\]

\[
\frac{V_{O}}{V_{IN}} \cdot (1 - \frac{V_{O}}{V_{IN}}) = \frac{1}{4} \text{ for } \frac{V_{IN}}{2} = V_{O}
\]

\[
C_{IN(MIN)} = \frac{1}{\left( \frac{V_{PP}}{I_{O}} - \text{ESR} \right) \cdot 4 \cdot F_{S}}
\]

Always examine the ceramic capacitor DC voltage coefficient characteristics when selecting the proper value. For example, the capacitance of a 10\( \mu \)F, 6.3V, X5R ceramic capacitor with 3.5V DC applied is actually about 5\( \mu \)F. Some examples of DC bias voltage versus capacitance for different package sizes are shown in Figure 1.

![Figure 1: 10\( \mu \)F Capacitor Value vs. DC Bias Voltage for Different Package Sizes.](image)

The maximum input capacitor RMS current is:

\[
I_{RMS} = I_{O} \cdot \sqrt{\frac{V_{O}}{V_{IN}} \cdot (1 - \frac{V_{O}}{V_{IN}})}
\]

The input capacitor RMS ripple current varies with the input and output voltage and will always be less than or equal to half of the total DC load current.

\[
\sqrt{\frac{V_{O}}{V_{IN}} \cdot (1 - \frac{V_{O}}{V_{IN}})} = \sqrt{D \cdot (1 - D)} = \sqrt{0.5^2} = 0.5
\]

for \( V_{IN} = 2 \cdot V_{O} \)

\[
I_{RMS(MAX)} = \frac{I_{O}}{2}
\]

The term \( \frac{V_{O}}{V_{IN}} \cdot (1 - \frac{V_{O}}{V_{IN}}) \) appears in both the input voltage ripple and input capacitor RMS current equations and is a maximum when \( V_{O} \) is twice \( V_{IN} \). This is why the input voltage ripple and the input capacitor RMS current ripple are a maximum at 50% duty cycle. The input capacitor provides a low impedance loop for the edges of pulsed current drawn by the AAT2113B. Low ESR/ESL X7R and X5R ceramic capacitors are ideal for this function. To minimize stray inductance, the capacitor should be placed as closely as possible to the IC. This keeps the high frequency content of the input current localized, minimizing EMI and input voltage ripple. The proper placement of the input capacitor (C1) can be seen in the evaluation board layout in the Layout section of this datasheet (see Figure 3).

A laboratory test set-up typically consists of two long wires running from the bench power supply to the evaluation board input voltage pins. The inductance of these wires, along with the low-ESR ceramic input capacitor, can create a high Q network that may affect converter performance. This problem often becomes apparent in the form of excessive ringing in the output voltage during load transients. Errors in the loop phase and gain measurements can also result.

Since the inductance of a short PCB trace feeding the input voltage is significantly lower than the power leads from the bench power supply, most applications do not exhibit this problem.

In applications where the input power source lead inductance cannot be reduced to a level that does not affect the converter performance, a high ESR tantalum or aluminum electrolytic should be placed in parallel with the low ESR/ESL bypass ceramic capacitor. This damps the high Q network and stabilizes the system.
Output Capacitor

The output capacitor limits the output ripple and prevents the output voltage droop during large load transitions. A 10μF to 22μF X5R or X7R ceramic capacitor typically provides sufficient bulk capacitance to stabilize the output during large load transitions and has the ESR and ESL characteristics necessary for low output ripple.

The output voltage droop due to a load transient is dominated by the capacitance of the ceramic output capacitor.

During a step increase in load current, the ceramic output capacitor alone supplies the load current until the loop responds. Within two or three switching cycles, the loop responds and the inductor current increases to match the load current demand. The relationship of the output voltage droop during the three switching cycles to the output capacitance can be estimated by:

$$C_{OUT} = \frac{3 \cdot \Delta I_{LOAD}}{V_{DROOP} \cdot F_S}$$

Once the average inductor current increases to the DC load level, the output voltage recovers. The above equation establishes a limit on the minimum value for the output capacitor with respect to load transients.

The internal voltage loop compensation also limits the minimum output capacitor value to 10μF. This is due to its effect on the loop crossover frequency (bandwidth), phase margin, and gain margin. Increased output capacitance will reduce the crossover frequency with greater phase margin.

Feedback Resistor Selection

Resistors R1 and R2 of Figure 5 program the output to regulate at a voltage higher than 0.6V for the AAT2113B adjustable version. To limit the bias current required for the external feedback resistor string while maintaining good noise immunity, the suggested value for R2 is 200kΩ. Table 1 summarizes the resistor values for various output voltages with R2 set to either 59kΩ or 200kΩ. Alternately, the feedback resistor may be calculated using the following equation:

$$R1 = \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) \cdot R2 = \left( \frac{1.8V}{0.6V} - 1 \right) \cdot 200k\Omega = 400k\Omega$$

The AAT2113B adjustable version, combined with an external feed forward capacitor (C2 in Figure 5), delivers enhanced transient response for extreme pulsed load applications. The suggested value for C2 is in the range of 22pF to 100pF.

<table>
<thead>
<tr>
<th>V_{OUT} (V)</th>
<th>R2 = 59kΩ</th>
<th>R2 = 200kΩ</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.0</td>
<td>39.2</td>
<td>133</td>
</tr>
<tr>
<td>1.1</td>
<td>49.9</td>
<td>165</td>
</tr>
<tr>
<td>1.2</td>
<td>59</td>
<td>200</td>
</tr>
<tr>
<td>1.3</td>
<td>68.1</td>
<td>232</td>
</tr>
<tr>
<td>1.4</td>
<td>78.7</td>
<td>267</td>
</tr>
<tr>
<td>1.5</td>
<td>88.7</td>
<td>301</td>
</tr>
<tr>
<td>1.6</td>
<td>97.6</td>
<td>332</td>
</tr>
<tr>
<td>1.7</td>
<td>107</td>
<td>365</td>
</tr>
<tr>
<td>1.8</td>
<td>118</td>
<td>400</td>
</tr>
<tr>
<td>2.5</td>
<td>187</td>
<td>634</td>
</tr>
</tbody>
</table>

Table 2: Feedback Resistor Selection for Adjustable Output Voltage Version.

Thermal Calculations

There are three types of losses associated with the AAT2113B step-down converter: switching losses, conduction losses, and quiescent current losses. Conduction losses are associated with the R_{DS(ON)} characteristics of the power output switching devices. Switching losses are dominated by the gate charge of the power output switching devices. At full load, assuming continuous conduction mode (CCM), a simplified form of the losses is given by:

$$P_{TOTAL} = I_o^2 \cdot (R_{DS(ON)H} \cdot V_o + R_{DS(ON)L} \cdot [V_{IN} - V_o]) \cdot \frac{V_{IN}}{V_{IN}} + (t_{sw} \cdot F_S \cdot I_o + I_o) \cdot V_{IN}$$

I_o is the step-down converter quiescent current. The term \( t_{sw} \) is used to estimate the full load step-down converter switching losses. For the condition where the step-down converter is in dropout at 100% duty cycle, the total device dissipation reduces to:

$$P_{TOTAL} = I_o^2 \cdot R_{DS(ON)H} + (t_{sw} \cdot F_S \cdot I_o + I_o) \cdot V_{IN}$$
Since $R_{\text{DS(ON)}}$, quiescent current, and switching losses all vary with input voltage, the total losses should be investigated over the complete input voltage range.

Given the total losses, the maximum junction temperature can be derived from the $\Theta_{JA}$ for the FTDFN22-8 package, which is 70°C/W.

$$T_{J(\text{MAX})} = P_{\text{TOTAL}} \cdot \Theta_{JA} + T_{\text{AMB}}$$

**PCB Layout Considerations**

The suggested PCB layout for the AAT2113B is shown in Figures 3 and 4 (fixed version) or Figures 6 and 7 (adjustable version). The following guidelines should be used to help ensure a proper layout:

1. The input capacitor (C1) should be connected as close as possible to VP and PGND.
2. The output capacitor and L1 should be connected as closely as possible. The connection of L1 to the LX pin should be as short as possible.
3. For the fixed output version, the feedback trace or FB pin should be separated from any power trace and connected as closely as possible to the load point. Sensing along a high-current load trace will degrade DC load regulation. For the adjustable version, the trace connecting the FB pin to resistors R1 and R2 should be as short as possible by placing R1 and R2 immediately next to the AAT2113B. The sense trace connection from R1 to the output voltage should be separate from any power trace and connect as closely as possible to the load point. The external feed-forward capacitor C2 should be connected as close as possible in parallel with R1 for enhanced transient response.
4. The resistance of the trace from the load return to PGND should be kept to a minimum. This will help to minimize any error in DC regulation due to differences in the potential of the internal signal ground and the power ground.
5. Connect unused signal pins to ground to avoid unwanted noise coupling.
3.3MHz, Fast Transient 1.5A Step-Down Converter in an 2mm x 2mm Package

U1  AAT2113BIXS-1.2V-T1  Skyworks, 3.3MHz Fast Transient, 1.5A Step-Down Converter, FTDFN22-8, 2x2mm
C1  GRM188R60J475KE19D, Murata, Cap, MLC, 4.7μF/6.3V, 0603 (HMAX = 0.9mm)
L1  LQM2HPNR47MGO, Murata, 0.47μH, ISAT = 1800mA, DCR = 40mΩ, 2.5 x 2 x 0.9 mm, shielded chip inductor
C2  GRM188R60J106ME47D, Murata, Cap, MLC, 10μF/6.3V, 0603 (HMAX = 0.9mm)
C3  GRM155R60J105KE19D, Murata, Cap, MLC, 1μF/6.3V, 0402

Figure 2: AAT2113B Evaluation Board Schematic For 1.2V Fixed Output Voltage Version.

Figure 3: AAT2113B Evaluation Board Top Side Layout for 1.2V Fixed Output Voltage Version.

Figure 4: AAT2113B Evaluation Board Bottom Side Layout for 1.2V Fixed Output Voltage Version.
3.3MHz, Fast Transient 1.5A Step-Down Converter in an 2mm x 2mm Package

U1 AAT2113BIXS-0.6-T1 Skyworks, 3.3MHz Fast Transient, 1.5A Step-Down Converter, FTDFN22-8, 2x2mm
C1 GRM188R60J475KE19D, Murata, Cap, MLC, 4.7μF/6.3V, 0603 (H_{MAX} = 0.8mm)
C2 Optional, 22pF, 0201
L1 LQM2HPN47MGO, Murata, 0.47μH, I_{SAT} = 1.8A, DCR = 0.04Ω, 2.5 x 2 x 1mm, shielded chip inductor
R1, R2 Carbon film resistor, 200kΩ, 1%, 0201
R3 Carbon film resistor, 0Ω
C3 GRM188R60J106ME47D, Murata, Cap, MLC, 10μF/6.3V, 0603 (H_{MAX} = 0.8mm)
C4 GRM155R60J105KE19D, Murata, Cap, MLC, 1μF/6.3V, 0402

Figure 5: AAT2113B Evaluation Board Schematic For Adjustable Output Voltage Version.

Figure 6: AAT2113B Evaluation Board

Figure 7: AAT2113B Evaluation Board

Top Side Layout for Adjustable Output Voltage Version.

Bottom Side Layout for Adjustable Output Voltage Version.
Figure 8: AAT2113B Application Schematic for 2.5V Output Voltage.
AAT2113B Design Example

Specifications

\[ V_{\text{OUT}} = 1.2\text{V} @ 1.5\text{A}, \text{Pulsed Load} \Delta I_{\text{LOAD}} = 1.5\text{A} \]

\[ V_{\text{IN}} = 3.3\text{V} \]

\[ F_S = 3.3\text{MHz} \]

\[ T_{\text{AMB}} = 85^\circ\text{C} \text{ in 8-pin 2x2mm DFN low profile package} \]

Output Inductor

For Murata, 0.47μH LQM2HPNNR47MG0 shielded chip inductor has a 40mΩ DCR.

\[ \Delta I = \frac{V_O}{L_1 \cdot F_S} \left[ 1 - \frac{V_O}{V_{\text{IN}}} \right] = \frac{1.2\text{V}}{0.47\mu\text{H} \cdot 3.3\text{MHz}} \left[ 1 - \frac{1.2\text{V}}{3.3\text{V}} \right] = 0.492\text{mA} \]

\[ I_{\text{PK}} = I_{\text{OUT}} + \frac{\Delta I}{2} = 1.5\text{A} + 0.271\text{A} = 1.75\text{A} \]

\[ P_{L_1} = I_{\text{OUT}}^2 \cdot \text{DCR} = 1.5\text{A}^2 \cdot 40\text{mΩ} = 90\text{mW} \]

Output Capacitor

For \( V_{\text{DROOP}} = 0.12\text{V} \) (10% Output Voltage)

\[ C_{\text{OUT}} = \frac{3 \cdot \Delta I_{\text{LOAD}}}{V_{\text{DROOP}} \cdot F_S} = \frac{3 \cdot 1.5\text{A}}{0.12\text{V} \cdot 3.3\text{MHz}} = 11.4\mu\text{F}; \text{use 10μF} \]

For \( V_{\text{DROOP}} = 0.06\text{V} \) (5% Output Voltage)

\[ C_{\text{OUT}} = \frac{3 \cdot \Delta I_{\text{LOAD}}}{V_{\text{DROOP}} \cdot F_S} = \frac{3 \cdot 1.5\text{A}}{0.06\text{V} \cdot 3.3\text{MHz}} = 22.7\mu\text{F}; \text{use 22μF} \]

\[ I_{\text{RMS(MAX)}} = \frac{1}{2 \cdot \sqrt{3}} \cdot \frac{V_{\text{OUT}} \cdot (V_{\text{IN(MAX)}} - V_{\text{OUT}})}{L \cdot F_S \cdot V_{\text{IN(MAX)}}} = \frac{1}{2 \cdot \sqrt{3}} \cdot \frac{1.2\text{V} \cdot (3.3\text{V} - 1.2\text{V})}{0.47\mu\text{H} \cdot 3.3\text{MHz} \cdot 3.3\text{V}} = 142\text{mA}_{\text{rms}} \]

\[ P_{\text{RMS}} = ESR \cdot I_{\text{RMS}}^2 = 5\text{mΩ} \cdot (142\text{mA})^2 = 0.1\text{mW} \]
Input Capacitor

For Input Ripple $V_{PP} = 30mV$

$$C_{IN} = \frac{1}{\left(\frac{V_{PP}}{I_{O}} - ESR\right) \cdot 4 \cdot F_S} = \frac{1}{\left(\frac{30mV}{1.5A} - 5m\Omega\right) \cdot 4 \cdot 3.3MHz} = 5\mu F; \text{ use } 4.7\mu F$$

$$I_{RMS} = \frac{I_{OUT1}}{2} = 0.75A$$

$$P = ESR \cdot (I_{RMS})^2 = 5m\Omega \cdot (0.75A)^2 = 2.8mW$$

AAT2113B Losses

All values assume 85°C ambient temperature and thermal resistance of 70°C/W in the 8-pin 2x2mm DFN low profile package.

$$P_{TOTAL} = I_{OUT}^2 \cdot R_{DS(ON)H} + (t_{SW} \cdot F_{SW} \cdot I_{OUT} + I_Q) \cdot V_{IN}$$

$$= 1.5A^2 \cdot 152m\Omega + (5ns \cdot 3.3MHz \cdot 1.5A + 50\mu A) \cdot 3.3V$$

$$= 423mW$$

$$T_{J(MAX)} = T_{AMB} + \Theta_{JA} \cdot P_{LOSS} = 85°C + (70°C/W) \cdot 423mW = 115°C$$
Ordering Information

<table>
<thead>
<tr>
<th>Output Voltage</th>
<th>Package</th>
<th>Marking(^1)</th>
<th>Part Number (Tape and Reel)(^2)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.2V</td>
<td>FTDFN22-8</td>
<td></td>
<td>AAT2113BIXS-1.2-T1</td>
</tr>
<tr>
<td>Adjustable (0.6V)</td>
<td>FTDFN22-8</td>
<td>K9XYY</td>
<td>AAT2113BIXS-0.6-T1</td>
</tr>
</tbody>
</table>

Skyworks Green™ products are compliant with all applicable legislation and are halogen-free.

For additional information, refer to Skyworks Definition of Green™, document number SQ04-0074.

Package Information

1. XYY = assembly and date code.
2. Sample stock is generally held on part numbers listed in **BOLD**.
3. The leadless package family, which includes QFN, TQFN, DFN, TDFN and STDFN, has exposed copper (unplated) at the end of the lead terminals due to the manufacturing process. A solder fillet at the exposed copper edge cannot be guaranteed and is not required to ensure a proper bottom solder connection.